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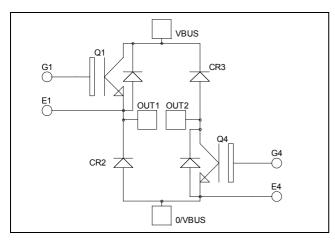


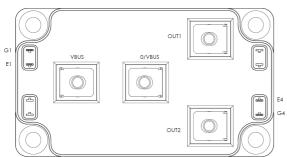






Asymmetrical - bridge NPT IGBT Power Module





 $V_{CES} = 600V$ $I_{C} = 180A$ @ Tc = 80°C

Application

- Welding converters
- Switched Mode Power Supplies
- Switched Reluctance Motor Drives

Features

- Non Punch Through (NPT) Fast IGBT®
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- Low profile
- RoHS compliant

Abs	sol	ute	maximum	ratings
~	_	_		_

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
Ţ	Continuous Collector Current	$T_c = 25^{\circ}C$	220	
I_{C}	Continuous Conector Current	$T_c = 80$ °C	180	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	630	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	833	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	400A @ 600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
T	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_i = 25$ °C			300	μA
I_{CES}	Zero Gate Voltage Collector Current	$V_{CE} = 600V$	$T_{i} = 125^{\circ}C$			1000	μΑ
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		2.0	2.5	V
$V_{CE(sat)}$	Conector Emitter Saturation Voltage	$I_{\rm C} = 180A$	$T_j = 125$ °C		2.2		v
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 2mA$		3		5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20 \text{ V}, V_{CE} = 0 \text{ V}$				±200	nA

Dynamic Characteristics

•	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			8.6		nF
C_{oes}	Output Capacitance				0.94		
C_{res}	Reverse Transfer Capacitance	f = 1MHz			0.8		
Q_{g}	Total gate Charge	$V_{GS} = 15V$			660		
Q_{ge}	Gate – Emitter Charge	$V_{Bus} = 300V$			580		nC
Q_{gc}	Gate – Collector Charge	$I_{\rm C} = 180 {\rm A}$			400		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch		26			
$T_{\rm r}$	Rise Time	$V_{GE} = 15V$			25		. [
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 400V$ $I_{C} = 180A$			150		ns
T_{f}	Fall Time	$R_G = 2.5 \Omega$		30			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_{C} = 180A$ $R_{G} = 2.5 \Omega$			26		ns
T_{r}	Rise Time				25		
$T_{d(off)}$	Turn-off Delay Time				170		
T_{f}	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$	$T_j = 125$ °C		8.6		.mo I
E_{off}	Turn-off Switching Energy	$I_C = 180A$ $R_G = 2.5 \Omega$	$T_j = 125$ °C		7		mJ

Diode ratings and characteristics

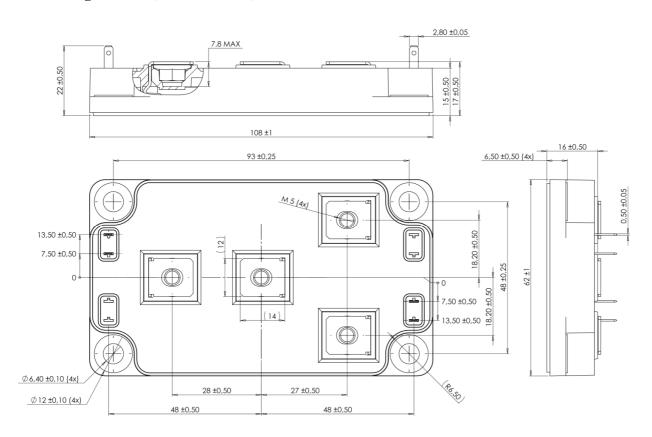
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_j = 25^{\circ}C$			350	μΑ
1RM	Waxinum Reverse Leakage Current	VR OOOV	$T_j = 125$ °C			750	μΑ
I_F	DC Forward Current		$T_c = 80$ °C		200		A
		$I_F = 200A$			1.6	1.8	
V_{F}	Diode Forward Voltage	$I_F = 400A$			1.9		V
		$I_F = 200A$	$T_j = 125$ °C		1.4		
t_{rr}	Reverse Recovery Time		$T_j = 25$ °C		180		ns
rr	Reverse Recovery Time	$I_F = 200A$ $V_R = 400V$	$T_{j} = 125^{\circ}C$		220		113
Q_{rr}	Reverse Recovery Charge	$di/dt = 400A/\mu s$	$T_j = 25^{\circ}C$		780		nC
₹rr			$T_{j} = 125^{\circ}C$		2900		110



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	L Junction to Case Thermal Resistance		IGBT			0.15	°C/W
T _{th} JC			Diode			0.32	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range Storage Temperature Range			-40		150	
T_{STG}				-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Torque	Woulding torque	For terminals	M5	2		3.5	11.111
Wt	Package Weight	•				300	g

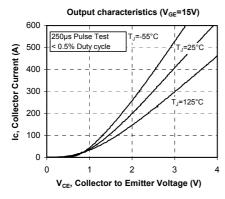
SP6 Package outline (dimensions in mm)

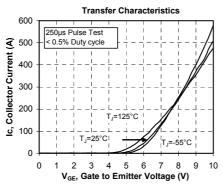


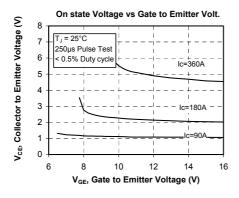
 $See \ application \ note \ APT0601 - Mounting \ Instructions \ for \ SP6 \ Power \ Modules \ on \ www.microsemi.com$

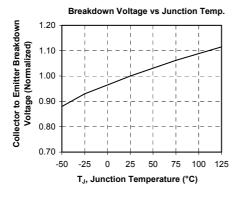


Typical Performance Curve

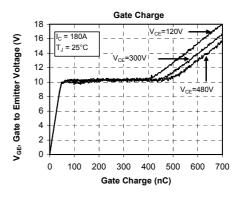


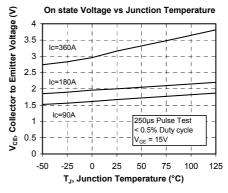


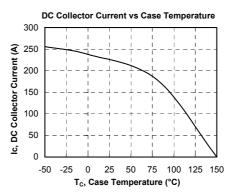




Output Characteristics (V_{GE}=10V) 600 250µs Pulse Test 500 < 0.5% Duty cycle ₹ Collector Current 400 T_J=25°C 300 200 T_{.i}=125°C 100 <u>ပ</u>် 0 3 V_{CE}, Collector to Emitter Voltage (V)



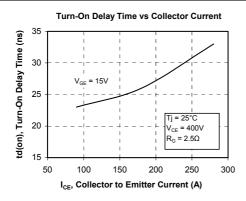


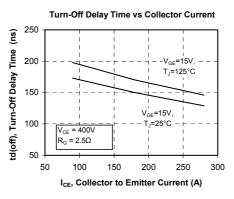


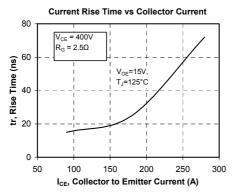
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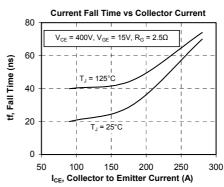
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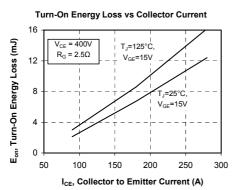


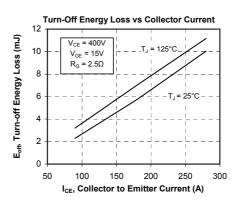


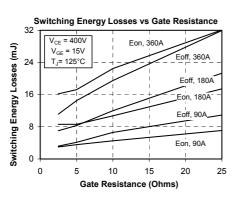


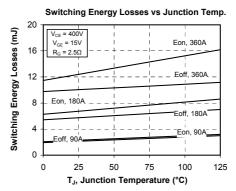




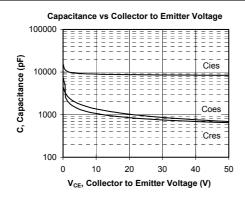


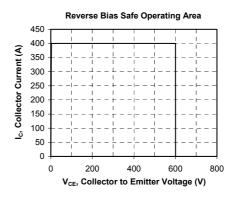


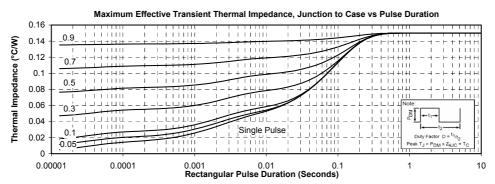


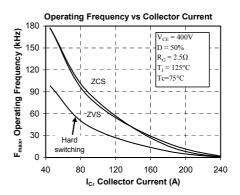














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